imall

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BC817-16/-25/-40

Taiwan Semiconductor

300mW, NPN Small Signal Transistor

FEATURES

- Low power loss, high efficiency
- Ideal for automated placement
- High surge current capability
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- Lighting application
- On-board DC/DC converter

MECHANICAL DATA

- Case: SOT-23
- Molding compound meets UL 94 V-0 flammability rating
- Moisture sensitivity level: level 1, per J-STD-020
- Packing code with suffix "G" means green compound (halogen-free)
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Weight: 8mg (approximately)

KEY PARAMETERS				
PARAMETER	VALUE	UNIT		
V _{CBO}	50	V		
V _{CEO}	45	V		
V _{EBO}	5	V		
Ι _C	500	mA		
h _{FE}	250-600			
Package	SOT-23			
Configuration	Single Dice			







ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise noted) BC817- BC817- BC817-PARAMETER SYMBOL UNIT 16 25 40 Marking code on the device 6A 6B 6C Power dissipation 300 P_D mW Collector-base voltage, emitter open 50 $I_{\rm C}$ = 10 μ A, $I_{\rm E}$ = 0 V_{CBO} V $I_{C} = 10 \text{ mA}, I_{B} = 0$ Collector-emitter voltage, base open 45 V_{CEO} ٧ 5 Emitter-base voltage, collector open $I_E = 1 \ \mu A, \ I_C = 0$ V_{EBO} V Collector current, dc 500 I_C mΑ T_J -55 to +150 °C Junction temperature T_{STG} -55 to +150 °C Storage temperature



BC817-16/-25/-40 Taiwan Semiconductor



ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)							
PARAMETER	CONDITIONS		SYMBOL	MIN	ТҮР	MAX	UNIT
Collector cutoff current, emitter open	$V_{CB}=45~V,~I_{E}=0$		I _{CBO}	-	-	0.1	μA
Emitter cutoff current, collector open	$V_{EB} = 4 \text{ V}, \text{ I}_{C} = 0$		I _{EBO}	-	-	0.1	μA
DC current gain	V _{CE} = 1 V, I _C = 100 mA	BC817-16	h _{FE}	100	-	250	
		BC817-25		160	-	400	
		BC817-40		250	-	600	
Collector-emitter saturation voltage	I _C = 500 mA, I _B = 50 mA		$V_{CE(sat)}$	-	-	0.7	V
Base-emitter saturation voltage	I _C = 500 mA, I _B = 50 mA		V _{BE(sat)}	-	-	1.2	V
Transition frequency	$V_{CE} = 5 V$, $I_C = 10 mA$, f= 100MHz		f⊤	100	-	-	MHz

ORDERING INFORMATION				
PART NO.	PACKING CODE	PACKING CODE SUFFIX(*)	PACKAGE	PACKING
BC817-XX (Note 1)	RF	G	SOT-23	3K / 7" Reel

Notes:

1. "xx" is Device Code is"16" and "25" and "40"

*: optional available

EXAMPLE					
EXAMPLE P/N	PART NO.	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION	
BC817-16 RFG	BC817-16	RF	G	Green compound	



CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

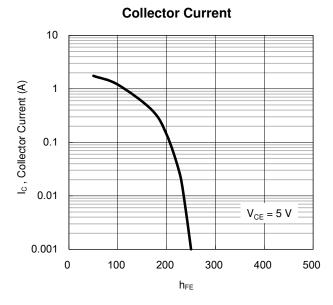


Fig.3 Base-Emitter Saturation Voltage

1000

100

10

1 └ 0.0

0.2

0.4

0.6

0.8

V_{BE}, Base-Emitter Voltage (V)

1.0

-Ic, Collector Current (mA)

Fig.1 Typical Pulsed Current Gain VS.

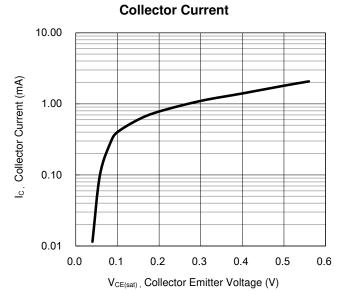
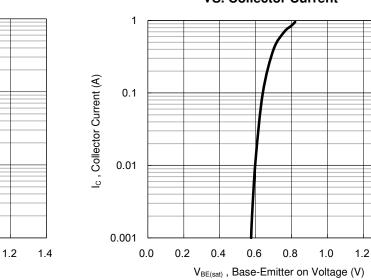


Fig. 2 Collector-Emitter Saturation Voltage VS.

Fig.4 Base-Emitter On Voltage VS. Collector Current



VS. Collector Current

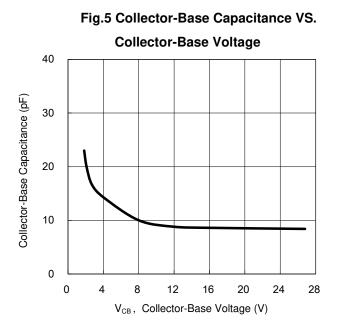
1.4



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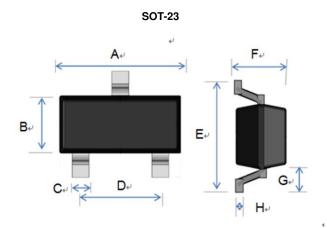
CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$



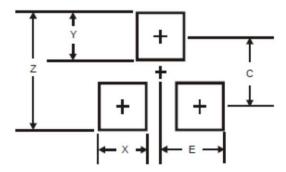


PACKAGE OUTLINE DIMENSION



DIM.	Unit(mm)		Unit(inch)	
	Min	Max	Min	Max
A	2.70	3.10	0.106	0.122
В	1.10	1.50	0.043	0.059
С	0.30	0.51	0.012	0.020
D	1.78	2.04	0.070	0.080
E	2.10	2.64	0.083	0.104
F	0.89	1.30	0.035	0.051
G	0.55 REF		0.022	REF
Н	0.10 REF		0.004	REF

SUGGEST PAD LAYOUT



DIM.	Unit(mm)	Unit(inch)	
	ТҮР	ТҮР	
Z	2.8	0.11	
Х	0.7	0.03	
Y	0.9	0.04	
С	1.9	0.07	
E	1.0	0.04	



BC817-16/-25/-40

Taiwan Semiconductor

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